

PATENT
4249-0110P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: AKKIPEDDI, Ramam et al. Conf.:
Appl. No.: NEW Group:
Filed: June 25, 2003 Examiner:
For: METHOD OF CLEAVING GAN/SAPPHIRE FOR
FORMING LASER MIRROR FACETS

PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

June 25, 2003

Sir:

The following preliminary amendments and remarks are respectfully submitted in connection with the above-identified application.

IN THE CLAIMS:

Please amend the claims as follows:

4. (Amended) A method according to claim 1, wherein the vertical planes are selected from one or more of the m-planes (1100) and the a-planes (1120).

6. (Amended) A method according to claim 2, wherein the thickness of the substrate is less than about 400 μm .